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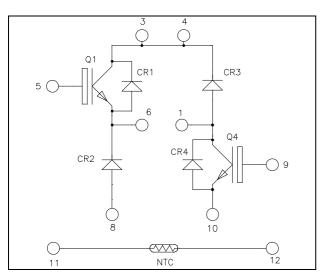


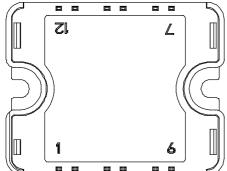


Asymmetrical - Bridge NPT IGBT Power Module

$$V_{CES} = 600V$$

 $I_C = 50A*$ @ $Tc = 80°C$





Pins 3/4 must be shorted together

Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Non Punch Through (NPT) Fast IGBT
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 100 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Very low stray inductance
 - Symmetrical design
 - Internal thermistor for temperature monitoring
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- RoHS Compliant

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Breakdown Voltage		600	V
T	Continuous Collector Current	$T_C = 25^{\circ}C$	65*	
I_{C}	Continuous Conector Current	$T_C = 80^{\circ}C$	50*	Α
I_{CM}	Pulsed Collector Current	$T_C = 25$ °C	230	
V_{GE}	Gate – Emitter Voltage		±20	V
P_{D}	Maximum Power Dissipation	$T_C = 25$ °C	250	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 125^{\circ}C$	100A @ 500V	

^{*} Specification of IGBT device but output current must be limited to 40A to not exceed a delta of temperature greater than 35°C for the connectors.

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit	
I	Zero Gate Voltage Collector Current	$V_{GE} = 0V$	$T_j = 25$ °C			250	^
I_{CES}	Zero Gate Voltage Collector Current	$V_{CE} = 600V$	$T_j = 125$ °C			500	μΑ
V _{CE(sat)}	Collector Emitter Saturation Voltage	$V_{GE} = 15V$	$T_j = 25$ °C	1.7	2.0	2.45	V
V CE(sat)	Conector Emitter Saturation Voltage	$I_C = 50A$	$T_j = 125$ °C		2.2		·
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$, $I_C = 1 \text{mA}$		4		6	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				400	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$ $V_{CE} = 25V$			2200		pF
C_{oes}	Output Capacitance				323		
C_{res}	Reverse Transfer Capacitance	f = 1MHz			200		
Q_{g}	Total gate Charge	$V_{GE} = 15V$			166		nC
Q_{ge}	Gate – Emitter Charge	$V_{Bus} = 300V$			20		
Q_{gc}	Gate – Collector Charge	$I_C = 50A$			100		
T _{d(on)}	Turn-on Delay Time	Inductive Switch	ning (25°C)		40		
$T_{\rm r}$	Rise Time	$V_{GE} = 15V$			9		
$T_{d(off)}$	Turn-off Delay Time	$V_{\text{Bus}} = 400V$ $I_{\text{C}} = 50A$			120		ns
T_{f}	Fall Time	$R_G = 2.7\Omega$		12			
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (125°C) $V_{GE} = 15V$ $V_{Bus} = 400V$ $I_{C} = 50A$ $R_{G} = 2.7\Omega$			42		ns
$T_{\rm r}$	Rise Time				10		
$T_{d(off)}$	Turn-off Delay Time				130		
$T_{\rm f}$	Fall Time				21		
Eon	Turn-on Switching Energy	$V_{GE} = 15V$ $V_{Bus} = 400V$	$T_j = 125$ °C		0.5		Т
E _{off}	Turn-off Switching Energy	$I_C = 50A$ $R_G = 2.7\Omega$	$T_j = 125^{\circ}C$	-	1		mJ
I_{sc}	Short Circuit data	$V_{GE} \le 15V$; V_{Bus} $t_p \le 10\mu s$; $T_i = 1$			225		A

Diode ratings and characteristics (CR2 & CR3)

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit	
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			600			V
I_{RM}	Maximum Reverse Leakage Current	$V_{p}=600V$	$T_j = 25^{\circ}C$	25°C 25	4		
1 _{RM}	Waximum Reverse Leakage Current		$T_{j} = 125^{\circ}C$			500	μA
I_{F}	DC Forward Current		$Tc = 80^{\circ}C$		30		A
		$I_F = 30A$			1.8	2.2	
$V_{\rm F}$	Diode Forward Voltage	$I_F = 60A$		2.2		V	
		$I_F = 30A$	$T_{j} = 125^{\circ}C$		1.5		
f	t_{rr} Reverse Recovery Time $I_F = 30A$ $V_R = 400V$	$T_j = 25$ °C		25		ns	
·rr		$T_{j} = 125^{\circ}C$		160		113	
Q _{rr}	Reverse Recovery Charge	$di/dt = 200 A/\mu s \qquad T_j = 25$	$T_j = 25$ °C		35		nC
			$T_j = 125$ °C		480		IIC

CR1 & CR4 are IGBT protection diodes only



Thermal and package characteristics

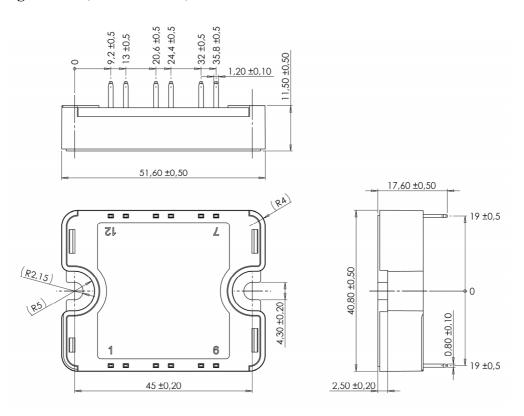
Symbol	Characteristic			Min	Typ	Max	Unit	
R_{thJC}	Junction to Case Thermal Resistance	IGB	Т			0.5	°C/W	
IX _{th} JC	Distribution to Case Thermal Resistance		Dio	de				1.2
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V	
T_{J}	Operating junction temperature range			-40		150		
T_{STG}	Storage Temperature Range			-40		125	°C	
$T_{\rm C}$	Operating Case Temperature				-40		100	
Torque	Mounting torque	To heatsink		M4	2	•	3	N.m
Wt	Package Weight					•	80	g

Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

Symbol	Characteristic		Min	Typ	Max	Unit
R ₂₅	Resistance @ 25°C			50		kΩ
$\Delta R_{25}/R_{25}$				5		%
$B_{25/85}$	$T_{25} = 298.15 \text{ K}$			3952		K
$\Delta B/B$		T _C =100°C		4		%

$$R_{T} = \frac{R_{25}}{\exp \left[B_{25/85} \left(\frac{1}{T_{25}} - \frac{1}{T} \right) \right]} \quad \text{T: Thermistor temperature} \\ R_{T}: \text{ Thermistor value at T}$$

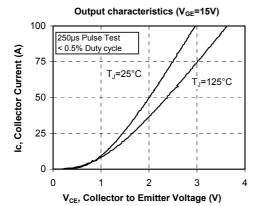
SP1 Package outline (dimensions in mm)

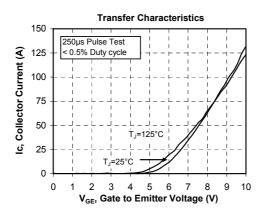


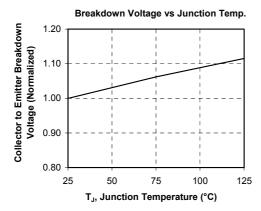
See application note 1904 - Mounting Instructions for SP1 Power Modules on www.microsemi.com

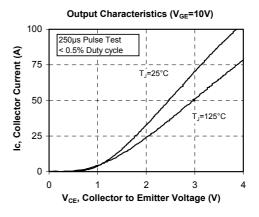


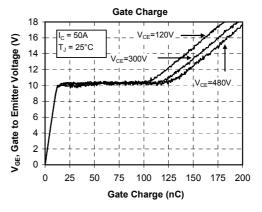
Typical IGBT Performance Curve

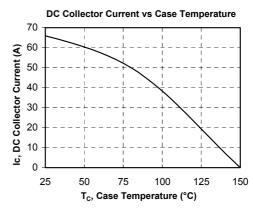




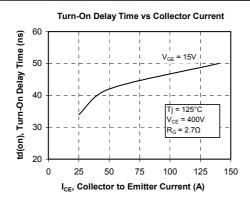


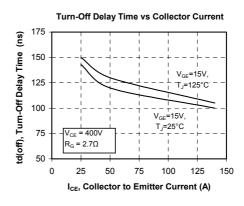


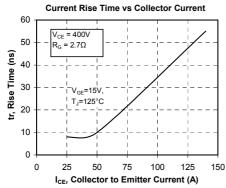


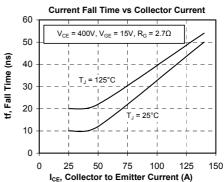


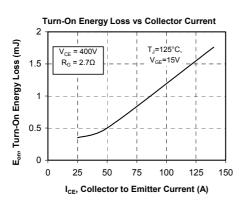


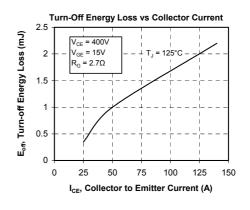


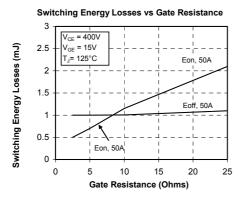


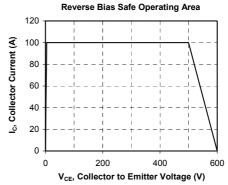




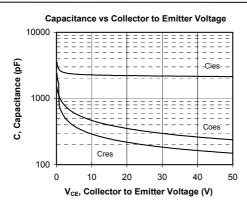


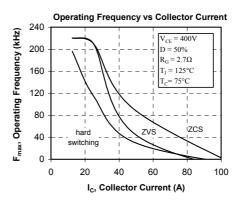


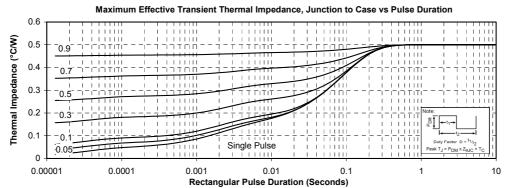








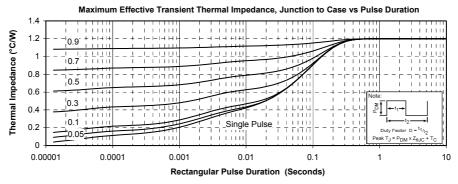


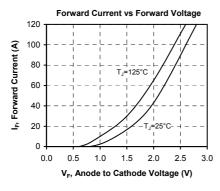


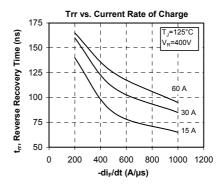
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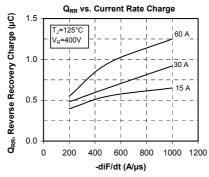


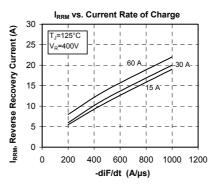
Typical diode Performance Curve

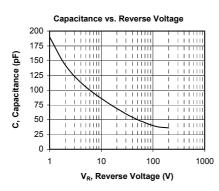


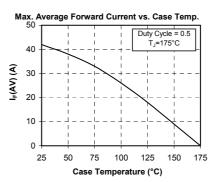












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